

STPS20SM60S

Power Schottky rectifier

Features

- High current capability
- Avalanche rated
- Low forward voltage drop
- High frequency operation

Description

The STPS20SM60S is a single Schottky diode, suited for high frequency switch mode power supply.

Packaged in TO-220AB, I²PAK and D²PAK, this device is intended to be used in notebook, game station and desktop adapters, providing in these aplications a good efficiency at both low and high load.

Table 1. Device summary

Symbol	Value
I _{F(AV)}	20 A
V _{RRM}	60 V
V _F (typ)	0.410 V
T _j (max)	150 °C

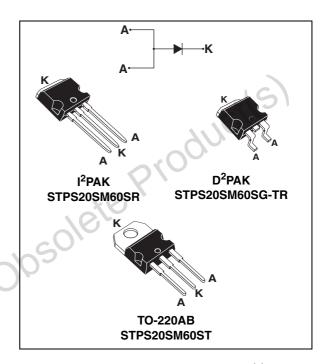
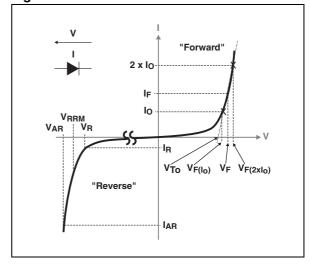


Figure 1. Electrical characteristics^(a)



V_{ARM} and I_{ARM} must respect the reverse safe operating area defined in *Figure 12*. V_{AR} and I_{AR} are pulse measurements (t_p < 1 μs). V_R, I_R, V_{RRM} and V_F, are static characteristics

Characteristics STPS20SM60S

Characteristics

Absolute ratings (limiting values with terminals 1 and 3 short circuited at Table 2. T_{amb} = 25 °C, unless otherwise specified)

Symbol	Parameter					Unit
V_{RRM}	Repetitive peak reverse vo	oltage			60	V
I _{F(RMS)}	Forward rms current				60	Α
I _{F(AV)}	Average forward current, $\delta = 0.5$ $T_c = 130 ^{\circ}\text{C}$ Per package					Α
I _{FSM}	Surge non repetitive forward	non repetitive forward current $t_p = 10 \text{ ms sine-wave}$				
P _{ARM} ⁽¹⁾	Repetitive peak avalanche	the power $T_j = 25$ °C, $t_p = 1 \mu s$			18400	W
V _{ARM} ⁽²⁾	Maximum repetitive peak avalanche voltage	t _p < 1 μs, T _j < 150 °C, I _{AR} < 69 A			80	V
V _{ASM} ⁽²⁾	Maximum single-pulse peak avalanche voltage	t _p < 1 μs, T _j <	80	V		
T _{stg}	Storage temperature rang	age temperature range				°C
T _j	Maximum operating junction temperature ⁽³⁾				150	°C

For temperature or pulse time duration deratings, please refer to Figure 4 and 5. More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the application notes AN1768 and AN2025.

Table 3. Thermal resistance

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	1.3	°C/W

Table 4. Static electrical characteristics (terminals 1 and 3 short circuited)

	Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
7/6	I _R ⁽¹⁾	Reverse leakage	T _j = 25 °C	V- - V	-	20	85	μΑ
, c0,	$I_{R}^{(1)}$ current $T_{j} = 125 ^{\circ}\text{C}$ $V_{R} = V_{RRM}$	ı	15	50	mA			
000	V _F ⁽²⁾ Forward voltage drop	Forward valtage drap	T _j = 25 °C	I _F = 10 A	-	0.495	0.535	V
			T _j = 125 °C		-	0.410	0.460	
		T _j = 25 °C	I - 20 A	-	0.570	0.630	'	
			T _j = 125 °C	I _F = 20 A	-	0.510	0.580	

^{1.} Pulse test: t_p = 5 ms, δ < 2 %

To evaluate the conduction losses use the following equation: P = 0.430 x $I_{F(AV)}$ + 0.0075 x $I_{F}^{2}_{(RMS)}$

$$P = 0.430 \times I_{F(AV)} + 0.0075 \times I_{F(RMS)}^2$$

^{2.} See Figure 12

 $[\]frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

^{2.} Pulse test: t_p = 380 μ s, δ < 2 %

STPS20SM60S Characteristics

Figure 2. Average forward power dissipation Figure 3. Average forward current versus versus average forward current ambient temperature ($\delta = 0.5$)

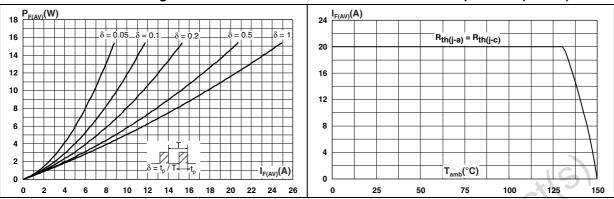


Figure 4. Normalized avalanche power derating versus pulse duration

Figure 5. Normalized avalanche power derating versus junction temperature

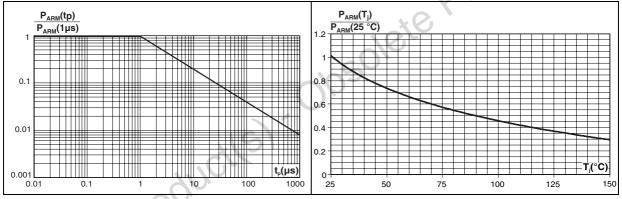
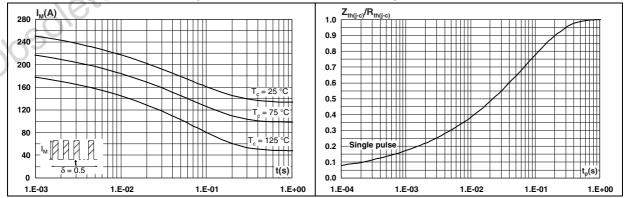


Figure 6. Non repetitive surge peak forward current versus overload duration (maximum values)

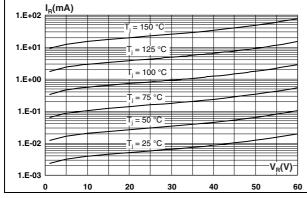
Figure 7. Relative variation of thermal impedance junction to case versus pulse duration



Characteristics STPS20SM60S

Figure 8. Reverse leakage current versus reverse voltage applied (typical values)

Figure 9. Junction capacitance versus reverse voltage applied (typical values)



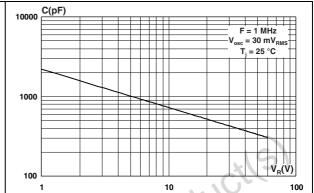
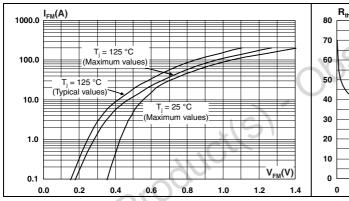


Figure 10. Forward voltage drop versus forward current

Figure 11. Thermal resistance junction to ambient versus copper surface under tab



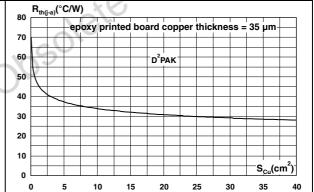
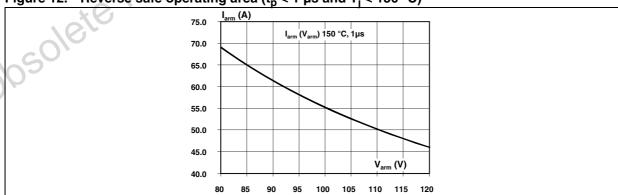


Figure 12. Reverse safe operating area (t_p < 1 μ s and T_j < 150 °C)



2 Package information

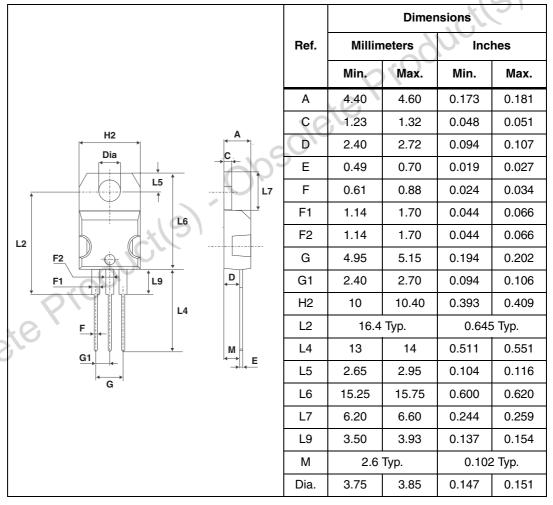
Epoxy meets UL94, V0

Cooling method: by conduction (C)

Recommended torque value: 0.4 to 0.6 N⋅m

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Table 5. TO-220AB dimensions



Package information STPS20SM60S

Table 6. D²PAK dimensions

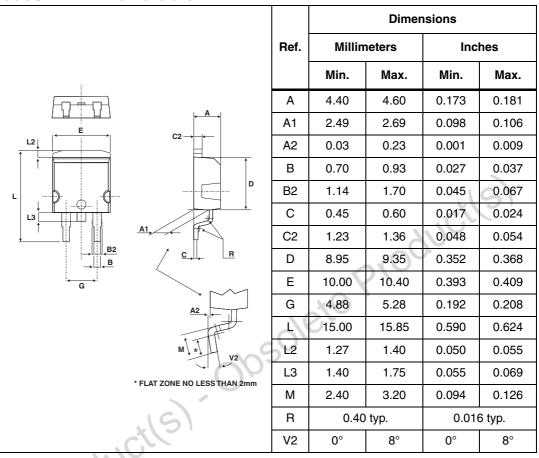
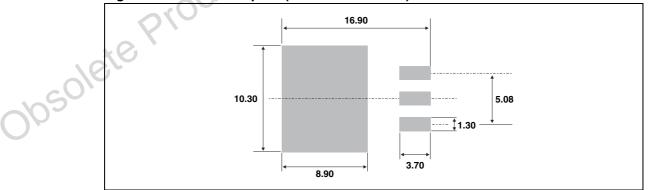
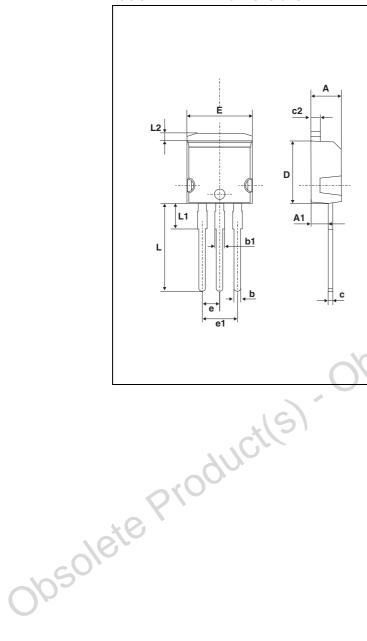


Figure 13. D²PAK footprint (dimensions in mm)



STPS20SM60S Package information

Table 7. I²PAK dimensions



	Dimensions					
Ref.	Millimeters		Inches			
	Min.	Min. Max.		Max.		
Α	4.40	4.60	0.173	0.181		
A1	2.40	2.72	0.094	0.107		
b	0.61	0.88	0.024	0.035		
b1	1.14	1.70	0.044	0.067		
С	0.49	0.70	0.019	0.028		
c2	1.23	1.32	0.048	0.052		
D	8.95	9.35	0.352	0.368		
е	2.40	2.70	0.094	0.106		
e1	4.95	5.15	0.195	0.203		
Е	10	10.40	0.394	0.409		
Д	13	14	0.512	0.551		
L1	3.50	3.93	0.138	0.155		
L2	1.27	1.40	0.050	0.055		

STPS20SM60S **Ordering information**

Ordering information 3

Table 8. **Ordering information**

Order code	Marking	Package	Weight Base qt		Delivery mode	
STPS20SM60ST	STPS20SM60ST	TO-220AB	2.2 g	50	Tube	
STPS20SM60SR	STPS20SM60SR	I ² PAK	1.49 g	50	Tube	
STPS20SM60SG-TR	STPS20SM60SG	D ² PAK	1.48 g	1000	Tape and reel	

Revision history 4

Table 9. **Revision history**

4	Revision his	story	a coduci(s)
	Date	Revision	Changes
	10-Oct-2011	1	Initial release.
Obsole	ate Produ	ct(s)	

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